Ordering number : EN8558

SANYO Semiconductors
DATA SHEET

2SC6015 — NPN Epitaxial Planar Silicon Transistor
DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT process.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Narrow h_{FE} range.
- High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		15	V
Collector-to-Emitter Voltage	V_{CEO}		15	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		9	A
Collector Current (Pulse)	I_{CP}		12	A
Base Current	I_B		1.2	A
Collector Dissipation	P_C	Mounted on a ceramic board (250mm²×0.8mm)	1.3	W
		Tc=25°C	3.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		−55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=12V, I_E=0A			0.1	μA
Emitter Cutoff Current	I_{EBO}	V_{EB}=4V, I_C=0A			0.1	μA
DC Current Gain	h_{FE}	V_{CE}=2V, I_C=500mA	250		400	

Marking : QC

Continued on next page.

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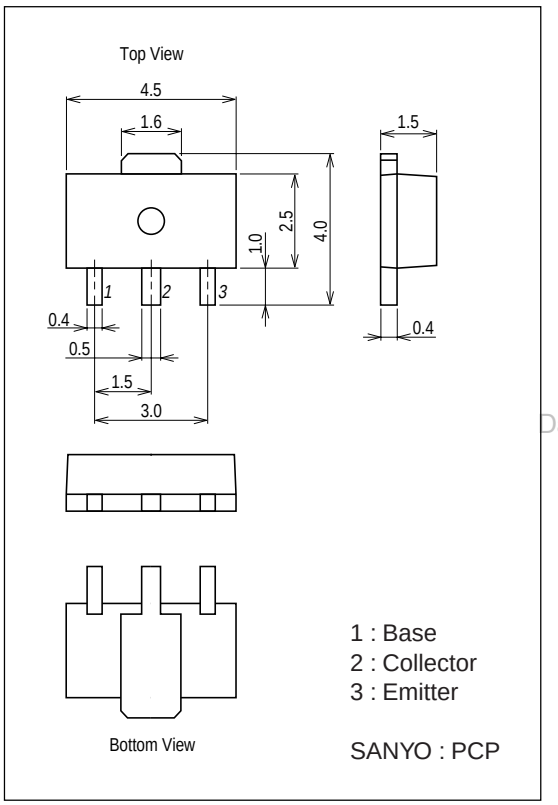
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	f_T	V_{CE}=2V, I_C=500mA		280		MHz
Output Capacitance	Cob	V_{CB}=10V, f=1MHz		50		pF
Collector-to-Emitter Saturation Voltage	V_{CE}(sat)	I_C=3A, I_B=60mA		90	135	mV
		I_C=4.5A, I_B=90mA		135	205	mV
Base-to-Emitter Saturation Voltage	V_{BE}(sat)	I_C=3A, I_B=60mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=10μA, I_E=0A	15			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA, R_{BE}=∞	15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0A	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}	See specified Test Circuit.		180		ns
Fall Time	t_f	See specified Test Circuit.		25		ns

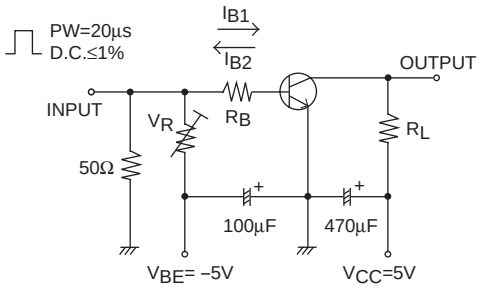
Package Dimensions

unit : mm

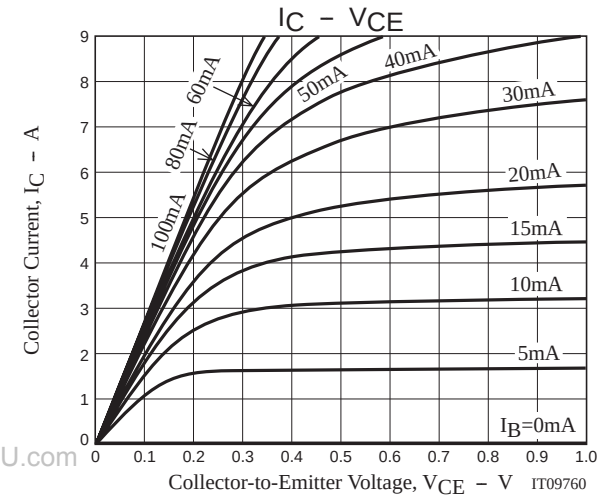
7008-003

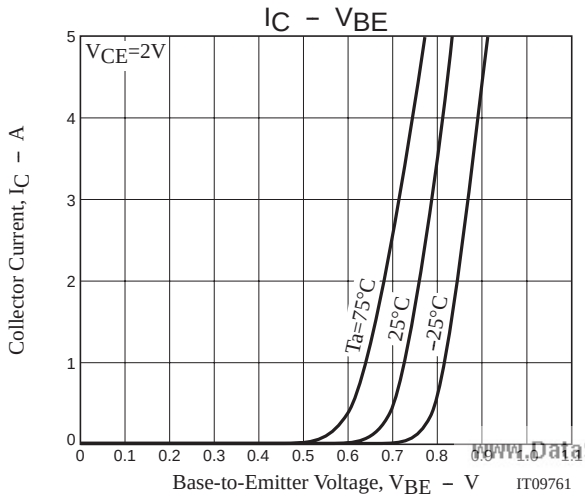


Switching Time Test Circuit

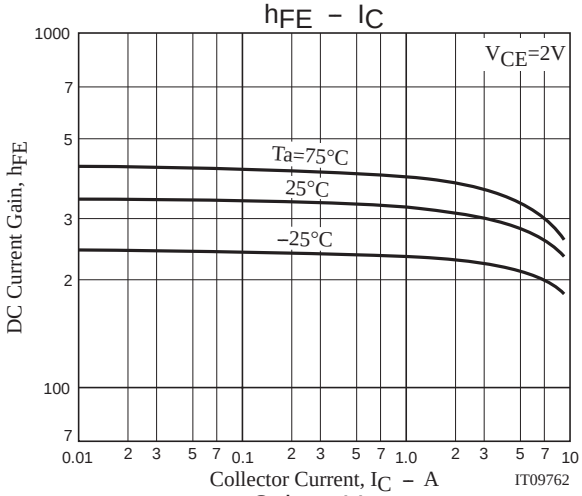


I_C=20I_{B1}= –20I_{B2}=3A

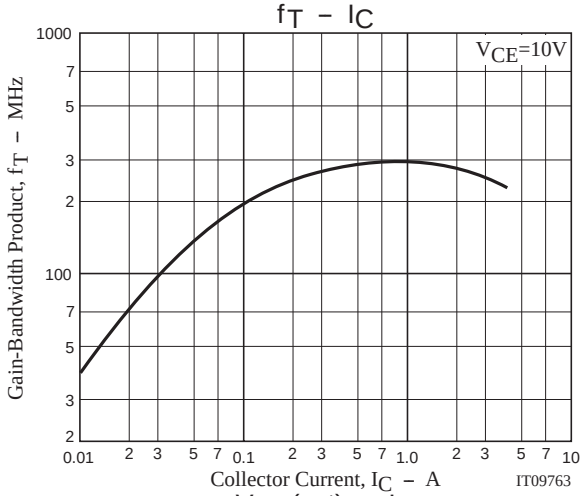




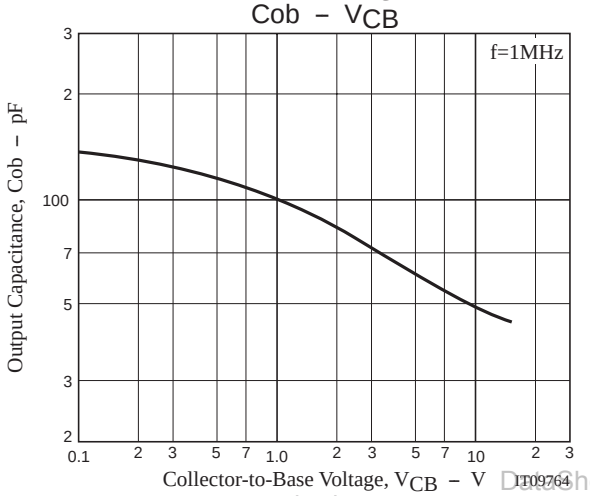
h_{FE} – I_C



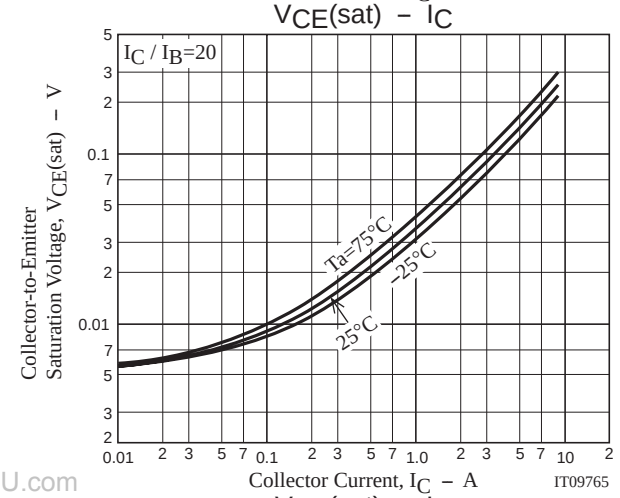
f_T – I_C



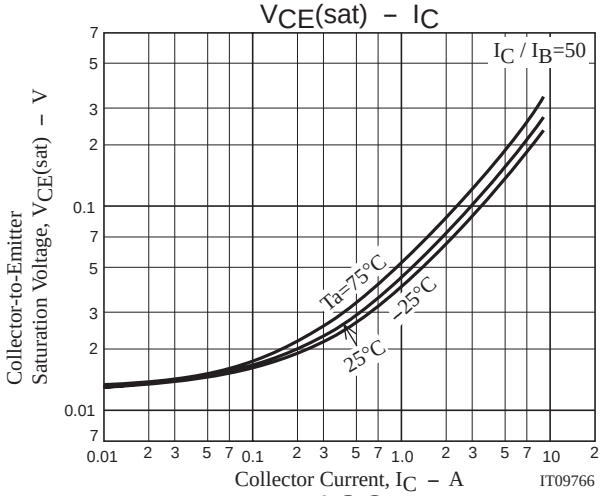
Cob – V_{CB}



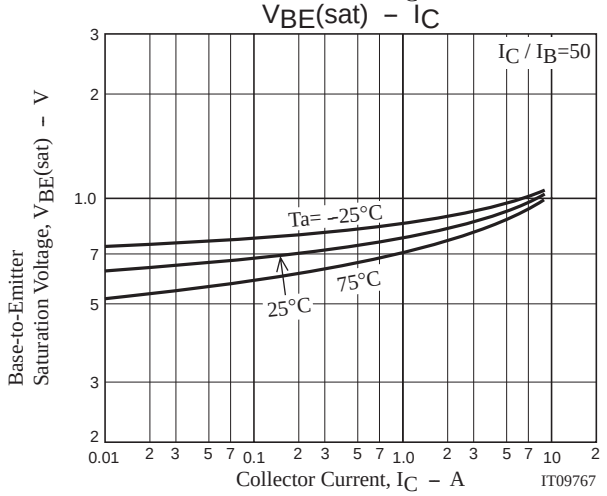
V_{CE}(sat) – I_C



V_{CE}(sat) – I_C



V_{BE}(sat) – I_C



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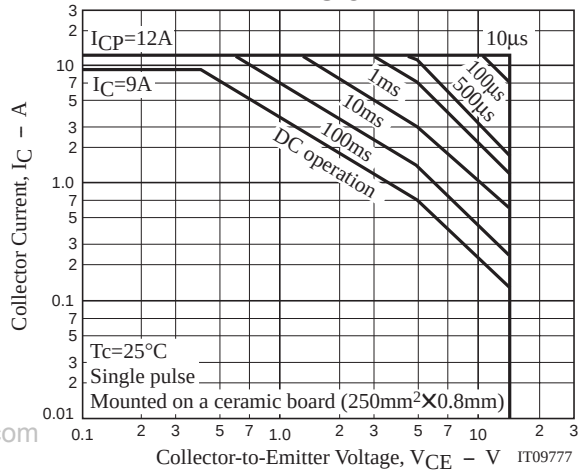
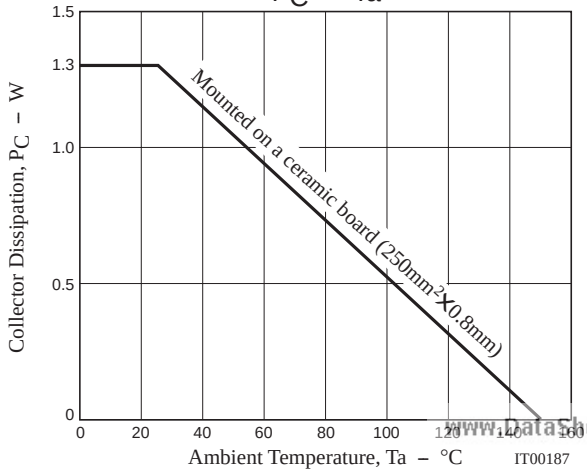
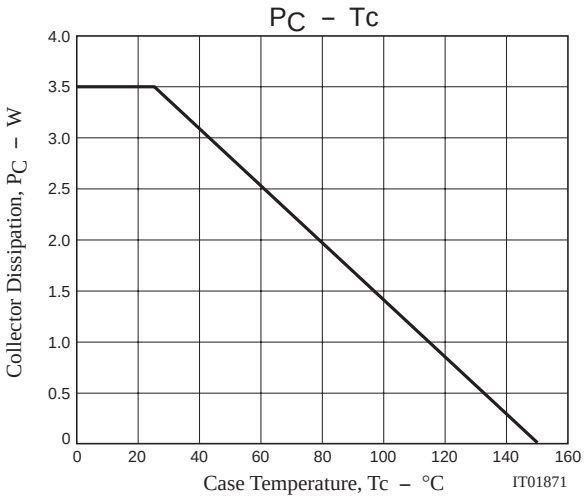


P_C – Ta





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